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# SN65C3222E, SN75C3222E 3-V TO 5.5-V MULTICHANNEL RS-232 LINE DRIVERS/RECEIVERS WITH $\pm 15$ -kV ESD PROTECTION

SLLS725A-JUNE 2006-REVISED JULY 2006

#### **FEATURES**

- ESD Protection for RS-232 Bus Pins
  - ±15-kV Human-Body Model (HBM)
  - ±8-kV IEC 61000-4-2, Contact Discharge
  - ±15-kV IEC 61000-4-2, Air-Gap Discharge
- Meet or Exceed the Requirements of TIA/EIA-232-F and ITU v.28 Standards
- Operate With 3-V to 5.5-V V<sub>CC</sub> Supply
- · Operate up to 1000 kbit/s
- Two Drivers and Two Receivers
- Low Standby Current . . . 1 μA Typ
- External Capacitors . . .  $4 \times 0.1 \mu F$
- Accepts 5-V Logic Input With 3.3-V Supply

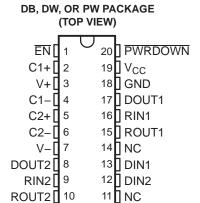
#### **APPLICATIONS**

- Battery-Powered Systems
- PDAs
- Notebooks
- Laptops
- Palmtop PCs
- Hand-Held Equipment

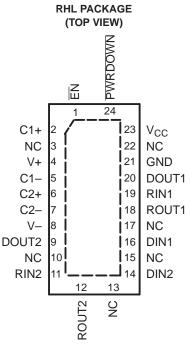
# DESCRIPTION/ ORDERING INFORMATION

The SN65C3222E and SN75C3222E consist of two line drivers, two line receivers, and a dual charge-pump circuit with  $\pm 15$ -kV ESD protection pin to pin (serial-port connection pins, including GND).

The devices meet the requirements of TIA/EIA-232-F and provide the electrical interface between an asynchronous communication controller and the serial-port connector. The charge pump and four small external capacitors allow operation from a single 3-V to 5.5-V supply. The devices operate at typical data signaling rates up to 1000 kbit/s and are improved drop-in replacements for industry-popular '3222 two-driver, two-receiver functions.



NC - No internal connection



NC - No internal connection

The SN65C3222E and SN75C3222E can be placed in the power-down mode by setting the power-down (PWRDOWN) input low, which draws only 1  $\mu$ A from the power supply. When the devices are powered down, the receivers remain active while the drivers are placed in the high-impedance state. Also, during power down, the onboard charge pump is disabled; V+ is lowered to V<sub>CC</sub>, and V- is raised toward GND. Receiver outputs also can be placed in the high-impedance state by setting enable (EN) high.

Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

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#### ORDERING INFORMATION

T <sub>A</sub>	P/	ACKAGE <sup>(1)</sup>	ORDERABLE PART NUMBER	TOP-SIDE MARKING
	SOIC - DW	Tube of 25	SN75C3222EDW	75C3222E
	30IC - DW	Reel of 2000	SN75C3222EDWR	7303222E
0°C to 70°C	SSOP – DB	Tube of 70	SN75C3222EDB	MY222E
0.0 10 70.0	220b – DB	Reel of 2000	SN75C3222EDBR	IVITZZZE
	TSSOP – PW	Tube of 70	SN75C3222EPW	MY222E
		Reel of 2000	SN75C3222EPWR	IVIT ZZZE
	SOIC - DW	Tube of 25	SN65C3222EDW	65C3222E
	SOIC - DW	Reel of 2000	SN65C3222EDWR	0303222E
–40°C to 85°C	SSOP – DB	Tube of 70	SN65C3222EDB	MU222E
-40°C 10 85°C	220b – DB	Reel of 2000	SN65C3222EDBR	IVIUZZZE
	TSSOP – PW	Tube of 70	SN65C3222EPW	MU222E
	1330F - PW	Reel of 2000	SN65C3222EPWR	IVIUZZZE

<sup>(1)</sup> Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

#### **FUNCTION TABLES**

#### Each Driver(1)

IN	PUTS	OUTPUT
DIN	<b>PWRDOWN</b>	DOUT
X	L	Z
L	Н	Н
Н	Н	L

(1) H = high level, L = low level, X = irrelevant, Z = high impedance

# Each Receiver<sup>(1)</sup>

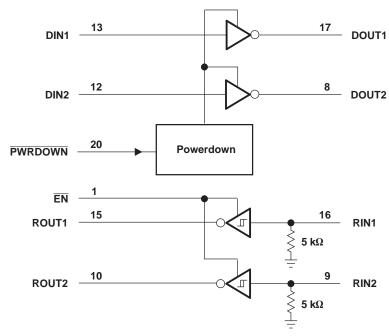
INPU	JTS	OUTPUT
RIN	EN	ROUT
L	L	Н
Н	L	L
X	Н	Z
Open	L	Н

<sup>(1)</sup> H = high level, L = low level, X = irrelevant,

Open = input disconnected or connected driver off

Z = high impedance (off),

### **LOGIC DIAGRAM (POSITIVE LOGIC)**



Pin numbers are for the DB, DW, and PW packages.

# **Absolute Maximum Ratings**(1)

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage range <sup>(2)</sup>		-0.3	6	V
V+	Positive-output supply voltage range <sup>(2)</sup>		-0.3	7	V
V-	Negative-output supply voltage range (2)		0.3	-7	V
V+ - V-	Supply voltage difference <sup>(2)</sup>			13	V
VI	land to take an area	Driver (EN, PWRDOWN)	-0.3	6	
	Input voltage range	Receiver	-25	25	V
.,	Output valtage range	Driver	-13.2	13.2	V
Vo	Output voltage range	Receiver	-0.3	V <sub>CC</sub> + 0.3	V
		DB package		70	
0	Deal and the second in a dame (3)(4)	DW package		58	0000
$\theta_{JA}$	Package thermal impedance (3)(4)	PW package		83	°C/W
		RHL package		TBD	
T <sub>J</sub>	Operating virtual junction temperature			150	°C
T <sub>stg</sub>	Storage temperature range		-65	150	°C

<sup>(1)</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

All voltages are with respect to network GND.

Maximum power dissipation is a function of  $T_J(max)$ ,  $\theta_{JA}$ , and  $T_A$ . The maximum allowable power dissipation at any allowable ambient temperature is  $P_D = (T_J(max) - T_A)/\theta_{JA}$ . Operating at the absolute maximum  $T_J$  of 150°C can affect reliability. The package thermal impedance is calculated in accordance with JESD 51-7.

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# Recommended Operating Conditions<sup>(1)</sup>

See Figure 5

				MIN	NOM	MAX	UNIT
	Supply voltage	$V_{CC} = 3.3 \text{ V}$	3	3.3	3.6	>	
	Supply voltage		$V_{CC} = 5 V$	4.5	5	5.5	V
V	Driver and control high-level input voltage	DIN, EN, PWRDOWN	$V_{CC} = 3.3 \text{ V}$	2			<b>&gt;</b>
V <sub>IH</sub>	Driver and control high-level input voltage	DIN, LIN, FWKDOWN	$V_{CC} = 5 V$	2.4			V
$V_{IL}$	Driver and control low-level input voltage	DIN, EN, PWRDOWN				8.0	>
$V_{I}$	Driver and control input voltage	DIN, EN, PWRDOWN		0		5.5	V
$V_{I}$	Receiver input voltage			-25		25	V
т	Operating free-air temperature		SN75C3222E	0		70	ů
IA	Operating nee-all temperature	SN65C3222E	-40		85	C	

<sup>(1)</sup> Test conditions are C1–C4 = 0.1  $\mu$ F at V<sub>CC</sub> = 3.3 V  $\pm$  0.3 V; C1 = 0.047  $\mu$ F, C2–C4 = 0.33  $\mu$ F at V<sub>CC</sub> = 5 V  $\pm$  0.5 V.

# Electrical Characteristics<sup>(1)</sup>

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 5)

	PARAMETER	TEST CONDITIONS	MIN	TYP <sup>(2)</sup>	MAX	UNIT
I	Input leakage current (EN, PWRDOWN)			±0.01	±1	μΑ
	Supply current	No load, PWRDOWN at V <sub>CC</sub>		0.3	1	mA
ICC	Supply current (powered off)	No load, PWRDOWN at GND		1	10	μΑ

<sup>(1)</sup> Test conditions are C1–C4 = 0.1  $\mu$ F at V<sub>CC</sub> = 3.3 V  $\pm$  0.3 V; C1 = 0.047  $\mu$ F, C2–C4 = 0.33  $\mu$ F at V<sub>CC</sub> = 5 V  $\pm$  0.5 V. (2) All typical values are at V<sub>CC</sub> = 3.3 V or V<sub>CC</sub> = 5 V, and T<sub>A</sub> = 25°C.

# SN65C3222E, SN75C3222E 3-V TO 5.5-V MULTICHANNEL RS-232 LINE DRIVERS/RECEIVERS WITH ±15-kV ESD PROTECTION

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#### **DRIVER SECTION**

#### Electrical Characteristics(1)

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 5)

PARAMETER		TEST CONDITIONS			TYP <sup>(2)</sup>	MAX	UNIT
$V_{OH}$	High-level output voltage	DOUT at $R_L = 3 \text{ k}\Omega$ to GND,	DIN = GND	5	5.4		V
$V_{OL}$	Low-level output voltage	DOUT at $R_L = 3 \text{ k}\Omega$ to GND,	$DIN = V_{CC}$	<b>-</b> 5	-5.4		V
I <sub>IH</sub>	High-level input current	$V_I = V_{CC}$	$V_1 = V_{CC}$		±0.01	±1	μΑ
I <sub>IL</sub>	Low-level input current	V <sub>I</sub> at GND			±0.01	±1	μΑ
I <sub>OS</sub>	Short-circuit output current <sup>(3)</sup>	V <sub>CC</sub> = 3.6 V V <sub>CC</sub> = 5.5 V	V <sub>O</sub> = 0 V		±35	±60	mA
r <sub>o</sub>	Output resistance	$V_{CC}$ , V+, and V- = 0 V,	V <sub>O</sub> = ±2 V	300	10M		Ω
	Output leakage current	PWRDOWN = GND	$V_{CC} = 3 \text{ V to } 3.6 \text{ V},$ $V_{O} = \pm 12 \text{ V}$			±25	^
I <sub>OZ</sub>		PWRDOWN = GND	$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V},$ $V_{O} = \pm 10 \text{ V}$			±25	μΑ

# Switching Characteristics<sup>(1)</sup>

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 5)

	PARAMETER		TEST CONDITIONS			TYP <sup>(2)</sup>	MAX	UNIT
		_	C <sub>L</sub> = 1000 pF		250			
	Maximum data rate (See Figure 1)	$R_L = 3 \text{ k}\Omega$ , One DOUT switching	$C_L = 250 \text{ pF},$	$V_{CC}$ = 3 V to 4.5 V	1000			kbit/s
	(CCC rigure 1)	one Boot omicining	$C_L = 1000 \text{ pF},$	$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	1000			
t <sub>sk(p)</sub>	Pulse skew <sup>(3)</sup>	$C_L = 150 \text{ pF to } 2500 \text{ pF},$	$R_L = 3 \text{ k}\Omega \text{ to } 7 \text{ k}\Omega,$	See Figure 2		300		ns
	Slew rate, transition region (see Figure 1)	Slew rate, $R_L = 7 \text{ k}\Omega$ ,			8		90	
SR(tr)		tion region	C <sub>L</sub> = 1000 pF		12		60	V/μs
		ee Figure 1) $R_L = 3 \text{ k}\Omega$			24		150	

<sup>(1)</sup> Test conditions are C1–C4 = 0.1  $\mu$ F at V<sub>CC</sub> = 3.3 V  $\pm$  0.3 V; C1 = 0.047  $\mu$ F, C2–C4 = 0.33  $\mu$ F at V<sub>CC</sub> = 5 V  $\pm$  0.5 V. (2) All typical values are at V<sub>CC</sub> = 3.3 V or V<sub>CC</sub> = 5 V, and T<sub>A</sub> = 25°C. (3) Pulse skew is defined as  $|t_{PLH} - t_{PHL}|$  of each channel of the same device.

Test conditions are C1–C4 = 0.1  $\mu$ F at V<sub>CC</sub> = 3.3 V  $\pm$  0.3 V; C1 = 0.047  $\mu$ F, C2–C4 = 0.33  $\mu$ F at V<sub>CC</sub> = 5 V  $\pm$  0.5 V. All typical values are at V<sub>CC</sub> = 3.3 V or V<sub>CC</sub> = 5 V, and T<sub>A</sub> = 25°C. Short-circuit durations should be controlled to prevent exceeding the device absolute power dissipation ratings, and not more than one output should be shorted at a time.

# SN65C3222E, SN75C3222E 3-V TO 5.5-V MULTICHANNEL RS-232 LINE DRIVERS/RECEIVERS WITH ±15-kV ESD PROTECTION

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#### RECEIVER SECTION

#### Electrical Characteristics(1)

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 5)

	PARAMETER	TEST CONDITIONS	MIN	TYP <sup>(2)</sup>	MAX	TINU
$V_{OH}$	High-level output voltage	$I_{OH} = -1 \text{ mA}$	V <sub>CC</sub> - 0.6	V <sub>CC</sub> - 0.1		٧
$V_{OL}$	Low-level output voltage	I <sub>OL</sub> = 1.6 mA			0.4	V
\/	Positive-going input threshold voltage	V <sub>CC</sub> = 3.3 V		1.5	2.4	V
V <sub>IT+</sub>	Positive-going input tilleshold voltage	V <sub>CC</sub> = 5 V		1.8	2.4	V
\/	Negative going input threshold voltage	V <sub>CC</sub> = 3.3 V	0.6	1.2		V
V <sub>IT</sub>	Negative-going input threshold voltage	V <sub>CC</sub> = 5 V	0.8	1.5		V
$V_{hys}$	Input hysteresis (V <sub>IT+</sub> - V <sub>IT-</sub> )			0.3		V
$I_{OZ}$	Output leakage current	EN = 1		±0.05	±10	μΑ
ri	Input resistance	$V_I = \pm 3 \text{ V to } \pm 25 \text{ V}$	3	5	7	kΩ

<sup>(1)</sup> Test conditions are C1–C4 = 0.1  $\mu$ F at V<sub>CC</sub> = 3.3 V  $\pm$  0.3 V; C1 = 0.047  $\mu$ F, C2–C4 = 0.33  $\mu$ F at V<sub>CC</sub> = 5 V  $\pm$  0.5 V. (2) All typical values are at V<sub>CC</sub> = 3.3 V or V<sub>CC</sub> = 5 V, and T<sub>A</sub> = 25°C.

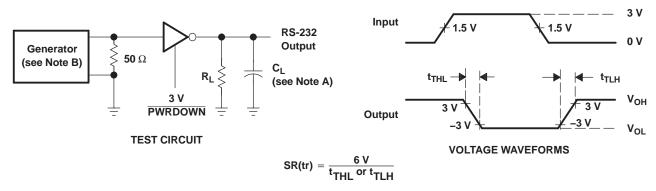
# Switching Characteristics<sup>(1)</sup>

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	TYP <sup>(2)</sup>	UNIT
t <sub>PLH</sub>	Propagation delay time, low- to high-level output	C <sub>L</sub> = 150 pF, See Figure 3	300	ns
t <sub>PHL</sub>	Propagation delay time, high- to low-level output	C <sub>L</sub> = 150 pF, See Figure 3	300	ns
t <sub>en</sub>	Output enable time	$C_L = 150 \text{ pF}, R_L = 3 \text{ k}\Omega, \text{ See Figure 4}$	200	ns
t <sub>dis</sub>	Output disable time	$C_L = 150 \text{ pF}, R_L = 3 \text{ k}\Omega, \text{ See Figure 4}$	200	ns
t <sub>sk(p)</sub>	Pulse skew <sup>(3)</sup>	See Figure 3	300	ns

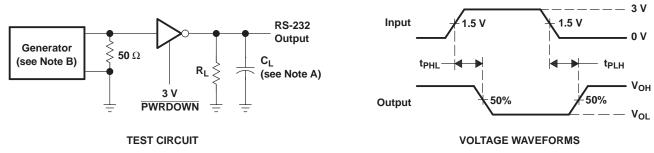
Test conditions are C1–C4 = 0.1  $\mu$ F at V<sub>CC</sub> = 3.3 V  $\pm$  0.3 V; C1 = 0.047  $\mu$ F, C2–C4 = 0.33  $\mu$ F at V<sub>CC</sub> = 5 V  $\pm$  0.5 V. All typical values are at V<sub>CC</sub> = 3.3 V or V<sub>CC</sub> = 5 V, and T<sub>A</sub> = 25°C. Pulse skew is defined as  $|t_{PLH} - t_{PHL}|$  of each channel of the same device.

#### PARAMETER MEASUREMENT INFORMATION



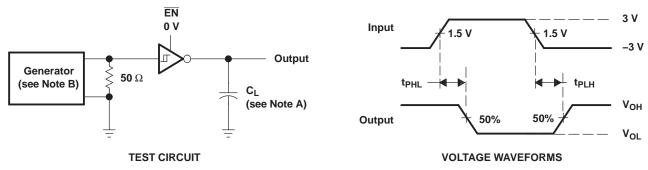
- A. C<sub>L</sub> includes probe and jig capacitance.
- B. The pulse generator has the following characteristics: PRR = 250 kbit/s,  $Z_0$  = 50  $\Omega$ , 50% duty cycle,  $t_r \le 10$  ns,  $t_f \le 10$  ns.

Figure 1. Driver Slew Rate



- A. C<sub>L</sub> includes probe and jig capacitance.
- B. The pulse generator has the following characteristics: PRR = 250 kbit/s,  $Z_O = 50 \Omega$ , 50% duty cycle,  $t_r \le 10$  ns,  $t_f \le 10$  ns.

Figure 2. Driver Pulse Skew

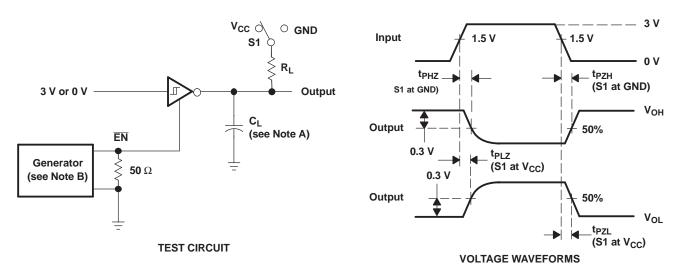


- A. C<sub>1</sub> includes probe and jig capacitance.
- B. The pulse generator has the following characteristics:  $Z_0$  = 50  $\Omega$ , 50% duty cycle,  $t_r \le 10$  ns,  $t_f \le 10$  ns.

Figure 3. Receiver Propagation Delay Times



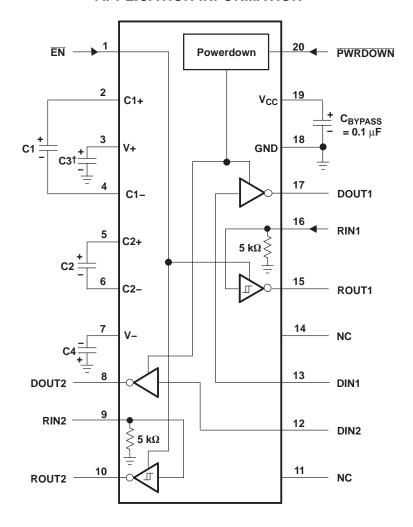
# PARAMETER MEASUREMENT INFORMATION (continued)



- A. C<sub>L</sub> includes probe and jig capacitance.
- B. The pulse generator has the following characteristics:  $Z_0$  = 50  $\Omega$ , 50% duty cycle,  $t_r \le 10$  ns.  $t_f \le 10$  ns.

Figure 4. Receiver Enable and Disable Times

#### **APPLICATION INFORMATION**



 $^{\dagger}$  C3 can be connected to  $V_{CC}\, or \, GND.$ 

NOTES: A. Resistor values shown are nominal.

- B. NC No internal connection
- C. Nonpolarized ceramic capacitors are acceptable. If polarized tantalum or electrolytic capacitors are used, they should be connected as shown.

#### **V<sub>CC</sub> vs CAPACITOR VALUES**

V <sub>CC</sub>	C1	C2, C3, and C4
3.3 V $\pm$ 0.3 V	<b>0.1</b> μ <b>F</b>	<b>0.1</b> μ <b>F</b>
5 V $\pm$ 0.5 V	<b>0.047</b> μ <b>F</b>	<b>0.33</b> μF
3 V to 5.5 V	<b>0.1</b> μF	<b>0.47</b> μ <b>F</b>

Figure 5. Typical Operating Circuit and Capacitor Values



# **PACKAGING INFORMATION**

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan <sup>(2)</sup>	Lead/Ball Finish	MSL Peak Temp <sup>(3)</sup>
SN65C3222EDB	ACTIVE	SSOP	DB	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN65C3222EDBG4	ACTIVE	SSOP	DB	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN65C3222EDBR	ACTIVE	SSOP	DB	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN65C3222EDBRG4	ACTIVE	SSOP	DB	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN65C3222EDW	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN65C3222EDWG4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN65C3222EDWR	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN65C3222EDWRG4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN65C3222EPW	ACTIVE	TSSOP	PW	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN65C3222EPWG4	ACTIVE	TSSOP	PW	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN65C3222EPWR	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN65C3222EPWRG4	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75C3222EDB	ACTIVE	SSOP	DB	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75C3222EDBG4	ACTIVE	SSOP	DB	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75C3222EDBR	ACTIVE	SSOP	DB	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75C3222EDBRG4	ACTIVE	SSOP	DB	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75C3222EDW	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75C3222EDWG4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75C3222EDWR	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75C3222EDWRG4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75C3222EPW	ACTIVE	TSSOP	PW	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75C3222EPWG4	ACTIVE	TSSOP	PW	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75C3222EPWR	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75C3222EPWRG4	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

 $<sup>^{(1)}</sup>$  The marketing status values are defined as follows:



#### PACKAGE OPTION ADDENDUM

6-Dec-2006

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

**Pb-Free** (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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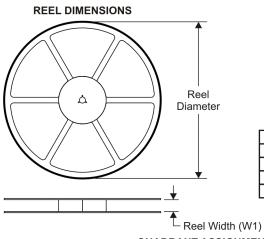
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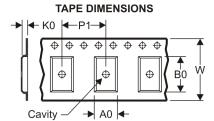




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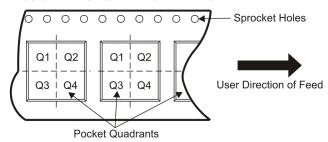
#### TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

# QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



\*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN65C3222EDBR	SSOP	DB	20	2000	330.0	16.4	8.2	7.5	2.5	12.0	16.0	Q1
SN65C3222EDWR	SOIC	DW	20	2000	330.0	24.4	10.8	13.0	2.7	12.0	24.0	Q1
SN65C3222EPWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.1	1.6	8.0	16.0	Q1
SN75C3222EDBR	SSOP	DB	20	2000	330.0	16.4	8.2	7.5	2.5	12.0	16.0	Q1
SN75C3222EDWR	SOIC	DW	20	2000	330.0	24.4	10.8	13.0	2.7	12.0	24.0	Q1
SN75C3222EPWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.1	1.6	8.0	16.0	Q1





\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN65C3222EDBR	SSOP	DB	20	2000	346.0	346.0	33.0
SN65C3222EDWR	SOIC	DW	20	2000	346.0	346.0	41.0
SN65C3222EPWR	TSSOP	PW	20	2000	346.0	346.0	33.0
SN75C3222EDBR	SSOP	DB	20	2000	346.0	346.0	33.0
SN75C3222EDWR	SOIC	DW	20	2000	346.0	346.0	41.0
SN75C3222EPWR	TSSOP	PW	20	2000	346.0	346.0	33.0

# PW (R-PDSO-G\*\*)

#### 14 PINS SHOWN

# PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.

D. Falls within JEDEC MO-153

# DW (R-PDSO-G20)

# PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MS-013 variation AC.



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